solid state communications

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VOLUME 119, NUMBER 1

(Published 26 June 2001)

CONTENTS

	v	Editorial
S.M. Kazakov, M. Angst, J. Karpinski, I.M. Fita and R. Puzniak	1	Substitution effect of Zn and Cu in MgB_2 on T_c and structure
M. Abplanalp, D. Barošová, P. Bridenbaugh, J. Erhart, J. Fousek, P. Günter, J. Nosek and M. Šulc	7	Ferroelectric domain structures in PZN-8%PT single crystals studied by scanning force microscopy
J. Wang, F. Ding, W. Shen, T. Li, G. Wang and J. Zhao	13	Thermal behavior of Cu-Co bimetallic clusters
J. Braddock-Wilking, SH. Lin and B.J. Feldman	19	¹³ C NMR spectroscopy of amorphous hydrogenated carbon — further evidence of inhomogeneity
R. Brüggemann, W. Bronner and M. Mehring	23	Influence of electron irradiation on the electronic properties of microcrystalline silicon
H. Kawamura, Y. Akahama, S. Umemoto, K. Takemura, Y. Ohishi and O. Shimomura	29	X-ray powder diffraction from solid deuterium
P. Galinetto, L. Malavasi and G. Flor	33	Structural investigation of high-T _c superconductor EuBa ₂ Cu ₃ O _y by microRaman spectroscopy
G. Vijaya Prakash, D. Narayana Rao and A.K. Bhatnagar	39	Linear optical properties of niobium-based tellurite glasses
J. Desforges and M.R. Singh	45	Model simulation of excitons in semiconductor nanostructures at high concentration and strong disorder
Y. Li, S. Xie, B. Wei, G. Lian, W. Zhou, D. Tang, X. Zou, Z. Liu and G. Wang	51	Aligned small α -SiC nanorods on β -SiC particles grown in an arc-discharge
W.G. Stallard, A.S. Plaut, S. Thoms, M.C. Holland, S.P. Beaumont, C.R. Stanley and M. Hopkinson	55	Fermi-edge singularities in a one-dimensional electron system in magnetic field
	I	Instructions to Authors
	III	Keywords
VOI	LUME	119, NUMBER 2

(Published 6 July 2001)

O. Voskoboynikov, H.C. Huang, C.F. Shi and C.P. Lee	59	Electron energy state spin-orbit splitting in nanoscopic quantum rings
D. Kumar, J. Narayan, T.K. Nath, A.K. Sharma, A. Kvit and C. Jin	63	Tunable magnetic properties of metal ceramic composite thin films
L. Mao, C. Tan and M. Xu	67	Measurements of the widths of transition regions at Si-SiO ₂ interfaces in metal-oxide-semiconductor structures from quantum oscillations in Fowler-Nordheim tunneling current
H.R. Schober	73	Isotope effect in the diffusion of binary liquids
Y. Matsuo, K. Takahashi and S. Ikehata	79	Evidence for proton conduction below superionic transition on Rb ₃ H(SeO ₄) ₂

E. Chappel, M.D. Núñez-Regueiro,G. Chouteau, A. Sulpice and C. Delmas	83	Low field magnetism and cationic distribution in quasi-stoichiometric $Li_{1-x}Ni_{1+x}O_2$
K.B. Cooper, M.P. Lilly, J.P. Eisenstein, T. Jungwirth, L.N. Pfeiffer and K.W. West	89	An investigation of orientational symmetry-breaking mechanisms in high Landau levels
S. Kervan, M. Acet and Y. Elerman	95	Magnetic properties of Gd _{1-x} Ce _x Mn ₂ Ge ₂ compounds
G. Silversmit, H. Poelman, L. Fiermans and R. De Gryse	101	An X-ray photoelectron diffraction study of a ${\rm TiO_2}(001)$ anatase single crystal mineral
E. Koch and S. Goedecker	105	Locality properties and Wannier functions for interacting systems
S. Orozco, R.M. Méndez-Moreno and M. Moreno	111	Magnetic character of the two-dimensional electron gas
	I	Instructions to Authors
	III	Keywords

VOLUME 119, NUMBER 3

(Published 17 July 2001)

K. Franke, G. Martin, M. Weihnach and A.V. Sotnikov	117	SrBi ₂ Ta ₂ O ₉ has only two polar axes – a problem for high density ferroelectric memory devices
D. Luis, J.P. Díaz, C. Otón, N.E. Capuj and H. Cruz	121	Tunneling escape process from a spin-polarized two-dimensional electron system
R.R. Das, W. Pérez, R.S. Katiyar and S.B. Krupanidhi	127	Study of Pulsed Laser Ablated CaBi ₂ Ta ₂ O ₉ Thin Films
L. Liu, Y.J. Feng, L.Y. Wu, Q.G. Liu, E.H. Zhao, Z.L. Fu, L. Kang, S.Z. Yang and P.H. Wu	133	Local microwave characterization of metal films using a scanning microwave near-field microscope
Z. Pajak, M. Polomska and J. Wolak	137	NIR FT Raman study of phase transitions in ferroelectric pyridinium periodate
W. Zhang, Z. Yang, X. Huang, S. Zhang, W. Yu, Y. Qian, Y. Jia, G. Zhou and L. Chen	143	Low temperature growth of bismuth sulfide nanorods by a hydrothermal method
L.x. Klopotowski, M. Nawrocki, J.A. Gaj, S. Maćkowski and E. Janik	147	Tunneling of spin polarized excitons in CdTe based asymmetric double quantum well structure
A.V. Tsvyashchenko, L.N. Fomicheva, M.V. Magnitskaya, E.N. Shirani, V.B. Brudanin, D.V. Filossofov, O.I. Kochetov, N.A. Lebedev, A.F. Novgorodov, A.V. Salamatin, N.A. Korolev, A.I. Velichkov, V.V. Timkin, A.P. Menushenkov, A.V. Kuznetsov, V.M. Shabanov and Z.Z. Akselrod	153	Electric field gradients in MgB ₂ synthesized at high pressure: 111 Cd TDPAC study and ab initio calculation
V.P.S. Awana, J. Nakamura, J. Lindén, M. Karppinen and H. Yamauchi	159	Magnetoresistance peak in the vicinity of the charge disproportionation/ordering transition in the $R_{1/3}Sr_{2/3}FeO_{3-\delta}$ (R=La, Pr) perovskite
N. Atenco-Analco, N.M. Makarov and F. Pérez-Rodríguez	163	Surface scattering frequency and optical absorptivity of exciton in quasi-two-dimensional quantum wells
T. Ressler, J. Wienold, R.E. Jentoft, O. Timpe and T. Neisius	169	Solid state kinetics of the oxidation of MoO ₂ investigated by time-resolved X-ray absorption spectroscopy

- Y.-J. Ye, R.S. Chen, F. Chen, J. Sun and J. Ladik
- 175 The effect of water environment on the hopping conductivity of an aperiodic nucleotide base stack
 - I Instructions to Authors
- III Keywords

VOLUME 119, NUMBER 4-5

(Published 25 July 2001)

CONTENTS

Spin Effects in Mesoscopic Systems A Special Issue of Solid State Communications

V. Pellegrini and A. Pinezuk	181	Preface — Spin effects in mesoscopic systems
S. Amaha, D.G. Austing, Y. Tokura, K. Muraki, K. Ono and S. Tarucha	183	Magnetic field induced transitions in the few-electron ground states of artificial molecules
J.M. Calleja, H.P. van der Meulen, J. Sanchez, R. Hey, K.J. Friedland and K. Ploog	191	New results on the magneto-luminescence of a two-dimensional electron gas around integer filling factors
G. Chen, D. Gammon, L.J. Sham and D.G. Steel	199	Zeeman coherence in single quantum dots
S. Das Sarma, J. Fabian, X. Hu and I. Žutić	207	Spin electronics and spin computation
A.E. Dementyev, P. Khandelwal, N.N. Kuzma, S.E. Barrett, L.N. Pfeiffer and K.W. West	217	OPNMR — a local probe of spin physics
HA. Engel, P. Recher and D. Loss	229	Electron spins in quantum dots for spintronics and quantum computation
D. Ferrand, A. Wasiela, S. Tatarenko, J. Cibert,G. Richter, P. Grabs, G. Schmidt,L.W. Molenkamp and T. Dietl	237	Applications of II-VI diluted magnetic semiconductors for magneto-electronics
M.A. Kastner and D. Goldhaber-Gordon	245	Kondo physics with single electron transistors
A.H. MacDonald and C.M. Canali	253	Quantum description of ferromagnet metal nanoparticles
M.D. Martín, L. Viña and E.E. Mendez	259	Ultrafast light-polarization dynamics in semiconductor micro- cavities
N.D. Mathur and P.B. Littlewood	271	The self-organised phases of manganites
H. Ohno, F. Matsukura and Y. Ohno	281	Spin-dependent phenomena in ferromagnetic/nonmagnetic III-V heterostructures
K. Park and J.K. Jain	291	The spin physics of composite fermions
V. Pellegrini and A. Pinczuk	301	Excitonic spin instabilities and continuous phase transitions in quantum Hall magnets
M. Rontani, F. Troiani, U. Hohenester and E. Molinari	309	Quantum phases in artificial molecules
C. Schüller, C. Steinebach and D. Heitmann	323	Spin- and charge-density excitations in quantum dots: a Raman study
G. Senatore, S. Moroni and D. Varsano	333	Spin effects in the 2D electron gas
R. Wiesendanger and M. Bode	341	Nano- and atomic-scale magnetism studied by spin-polarized scanning tunneling microscopy and spectroscopy
	I	Author Index
	IV	Instructions to Authors
	VI	Keywords

VOLUME 119, NUMBER 6

(Published 31 July 2001)

	v	Editorial
I. Hiromitsu, Y. Murakami and T. Ito	357	A non-ideal bias dependence of the inner electric field in Au / Zn-phthalocyanine / Al photovoltaic cells studied by electro-absorption and photocurrent measurements
Z.W. Liu, S.N. Zhu, Y.Y. Zhu, H. Liu, Y.Q. Lu, H.T. Wang, N.B. Ming, X.Y. Liang and Z.Y. Xu	363	A scheme to realize three-fundamental-colors laser based on quasi-phase matching
WH. Seo and BH. Han	367	Many body effects on the linewidth enhancement factor of strained quantum wire lasers
M. Ghali, J. Kossut, E. Janik, K. Regiński and L.X. Klopotowski	371	Optical injection of spin-polarized carriers across a strongly mismatched heterostructure
M.X. Dai, C. Su, R. Wang and Z.L. Wang	377	A new phase in polycrystalline magnetoresistive Sr ₂ FeMoO ₆
X.L. Liang, Y. Chen, H.M. Shen, Z.F. Zhang, W. Li and Y.N. Wang	381	Thermal cycling stability and two-way shape memory effect of Ni-Cu-Ti-Hf alloys
X. Guo, Z. Chen, Y. Zhou, S. Dai, L. Liu, R. Li and D. Zheng	387	Effects of strain and grain size on the transport and magnetic anisotropic properties of $(La_{1-x}Sn_x)_yMnO_{3-\delta}$ epitaxial films
L. Sun, C. Qian, C. Liao, X. Wang and C. Yan	393	Luminescent properties of Li ⁺ doped nanosized Y ₂ O ₃ :Eu
X. Liu, G. Xu, Y. Sui, Y. He and X. Bao	397	Investigations into electron spin resonance in doped nanocrystalline silicon films
H. Chang, X. Zhang and Y. Yang	403	A study on the effect of hydrogen in the compounds with BaCd ₁₁ -type structure
Y. Jin, B. Zhang, S. Yang, Y. Wang, J. Chen, H. Zhang, C. Huang, C. Cao, H. Cao and R.P.H. Chang	409	Room temperature UV emission of $Mg_xZn_{1-x}O$ films
T. Yamasaki, K. Matsui, H. Nakamura and M. Shiga	415	Nearly antiferromagnetic metal with linear spin chains: $LaMn_4Al_8$
T. Makino, M. Watanabe and T. Hayashi	419	Line width of the biexciton states in PbI ₂ estimated from the analysis of reflection-type four-wave mixing spectra
	I	Instructions to Authors
	Ш	Keywords
VO	LUME	119, NUMBER 7
(Pub	olished	3 August 2001)
	CO	NTENTS
Y. Mudryk, O. Isnard, L. Romaka and D. Fruchart	423	Crystal structure and magnetic properties of RCu ₅ Sn compounds (R-Y, Gd-Yb)
V.B. Kokshenev	429	Ergodicity failure near structural glass transformations
D.N. Krizhanovskii, G. Dasbach, A.A. Dremin, V.D. Kulakovskii, N.A. Gippius, M. Bayer and A. Forchel	435	Impact of exciton localization on the optical non-linearities of cavity polaritons

JM. Liu, Y.W. Du, Z.G. Liu, H.L.W. Chan and C.L. Choy	441	Remanence enhancement of Potts spin lattice: Monte-Carlo simulation
A.V. Gomonnai, Yu.M. Azhniuk, M. Kranjčec, A.M. Solomon, V.V. Lopushansky and I.G. Megela	447	Effect of X-ray irradiation on $CdS_{1-x}Se_x$ quantum dots optical absorption
T. Klempt, S. Schweizer, K. Schwartz, O. Kanert, D. Suter, U. Rogulis and JM. Spaeth	453	Magnetic resonance investigation of the dynamics of F centers in LiF
JM. Liu, N. Chong, H.L.W. Chan and C.L. Choy	459	Scaling on hysteresis in a model spin system
J.H. Cho, S.J. Kim and Y.S. Yang	465	Structural change in $Bi_4(Si_xGe_{1-x})_3O_{12}$ glasses during crystallization
Z. Zou, J. Ye and H. Arakawa	471	Optical and structural properties of the BiTa _{1-x} Nb _x O ₄ ($0 \le x \le 1$) compounds
	I	Instructions to Authors
	III	Keywords

VOLUME 119, NUMBERS 8-9

(Published 21 August 2001)

N.E. Christensen and D.L. Novikov	477	High-pressure phases of the light alkali metals
M.A. Hayward, M.K. Haas, A.P. Ramirez, T. He, K.A. Regan, N. Rogado, K. Inumaru and R.J. Cava	491	The suppression of superconductivity in MgCNi ₃ by Ni-site doping
A. Melikyan and H. Minassian	497	Interaction of vibrational modes in ultrathin metallic films following femtosecond excitation
J.F. Willart, A. De Gusseme, S. Hemon, G. Odou, F. Danede and M. Descamps	501	Direct crystal to glass transformation of trehalose induced by ball milling
W.S. Kim, E.O. Chi, J.C. Kim, H.S. Choi and N.H. Hur	507	Close correlation among lattice, spin, and charge in the manganese-based antiperovskite material
K. Osuch	511	Symmetry changes at the Néel point in the high-T _c superconductor YbBa ₂ Cu ₃ O ₇
S. Zouari, L. Ranno, A. Cheikh-Rouhou, M. Pernet and P. Strobel	517	Effect of A-cation size variance on structural and physical properties of praseodymium manganites $Pr_{0.85}(Na_{1-x}K_x)_{0.15}MnO_3$
T. Nakamoto, M. Nakada and A. Nakamura	523	Magnetic study of pentavalent neptunium phthalate hexahydrate $(NpO_2)_2(O_2C)_2C_6H_4\cdot 6H_2O$
TY. Kim, H.M. Jang and S.M. Cho	527	Short-ranged clusters with tetragonal symmetry in La-modified PbTiO ₃ relaxor ferroelectrics
J. Weszka, P. Daniel, A.M. Burian, A. Burian and M. Żelechower	533	Temperature dependence of Raman scattering in amorphous films of $In_{1-x}Se_x$ alloys
HC. Freiheit	539	Order parameter behaviour and thermal hysteresis at the phase transition in the superionic conductor lithium sodium sulfate LiNaSO ₄
G. Busiello, R.V. Saburova and V.G. Sushkova	545	Dynamical effects in quantum droplet model of Ising spin glass in a transverse field
S.M. Moussa, B.J. Kennedy and T. Vogt	549	Structural variants in ABO ₃ type perovskite oxides. On the structure of BaPbO ₃

- O. Pană, L.V. Giurgiu, S. Knorr, J. Rahmer, A. Grupp and M. Mehring
- Soliton excitations in the quasi-one-dimensional conductor $Rb_2Pt(CN)_4(FHF)_{0.4}$
 - I Author Index
- VI Instructions to Authors
- VIII Keywords

VOLUME 119, NUMBERS 10-11

(Published 21 August 2001)

K. Kuriyama, H. Kondo and M. Okada	559	A point defect complex related to the yellow luminescence in electron irradiated GaN
A.G. Mal'shukov, Z. Ma, V.B. Antonyuk and K.A. Chao	563	Multilayer thermionic transport in semiconductor superlattices
E.G. Maksimov and D.Yu. Savrasov	569	Lattice stability and superconductivity of the metallic hydrogen at high pressure
H.J. Yuan, P. Xie, J. Xiang, D.P. Yu, J. Xu, S.S. Xie and S.Q. Feng	573	Transport property investigation of pure and Au-doped carbon nanotubes
Z.A. Ren, G.C. Che, H. Xiong, K.Q. Li, Y.S. Yao, D.N. Zheng, Y.M. Ni, S.L. Jia, C. Dong, H. Chen, J.L. Shen and Z.X. Zhao	579	Coexistence of magnetism and superconductivity in a new Fecontaining cuprate superconductor (Fe $_{0.5}$ Cu $_{0.5}$)SrBaYCu $_2$ O $_{7+\delta}$
W.T. Geng, A.J. Freeman and G.B. Olson	585	Influence of alloying additions on the impurity induced grain boundary embrittlement
C.B. Azzoni, M.C. Mozzati, L. Malavasi, P. Ghigna and G. Flor	591	Magnetic and X-ray diffraction investigation on $Mg_{1-x}Mn_{2+x}O_4$ spinels
B. Cage, P. Nguyen and N. Dalal	597	Three-dimensional antiferromagnetism in triamminodiperoxy-chromate, $Cr(NH_3)_3(O_2)_2$: a precursor to a new class of $Cr(IV)$ magnets
T. Tachiwaki, M. Yoshinaka, K. Hirota,T. Ikegami and O. Yamaguchi	603	Novel synthesis of $Y_3Al_5O_{12}$ (YAG) leading to transparent ceramics
H. Chang, X. Zhang and Y. Yang	607	The first-order magnetization process (FOMP) in NdFe ₉ Si ₂ C _x $(x = 0.5, 1.0, 1.5)$
Y.S. Nam, H.L. Ju and C.W. Park	613	Low field magnetoresistance in intrinsic granular system $La_{1-x}Ba_xMnO_3$
S.E. Kulkova, D.V. Valujsky, J.S. Kim, G. Lee and Y.M. Koo	619	Electronic structure of binary and ternary Ti-based shape- memory alloys
R. Feder and H. Gollisch	625	Selection rules in (e,2e) spectroscopy from surfaces
X. Leyronas and M. Combescot	631	Quantum wells, wires and dots with finite barrier: analytical expressions for the bound states
D.K. Powell, K.P. Starkey, G. Shaw, Y.V. Sushko, L.K. Montgomery and J.W. Brill	637	ac-Calorimetry of (TMTSF) ₂ PF ₆
	I	Instructions to Authors
	III	Keywords

VOLUME 119, NUMBER 12

(Published 5 September 2001)

W. Pan, H.L. Stormer, D.C. Tsui, L.N. Pfeiffer, K.W. Baldwin and K.W. West	641	Experimental evidence for a spin-polarized ground state in the $\nu=5/2$ fractional quantum Hall effect
V.L. Berkovits, A.B. Gordeeva and V.A. Kosobukin	647	Local-field effects in reflectance anisotropy spectra of oxidized (001) GaAs and AlGaAs surfaces
G. Seifert, T. Köhler, Z. Hajnal and T. Frauenheim	653	Tubular structures of germanium
MS. Zhang, Z. Yin, Q. Chen, W. Zhang and W. Chen	659	Study of structural and photoluminescent properties in barium titanate nanocrystals synthesized by hydrothermal process
YX. Wang, WL. Zhong, CL. Wang and PL. Zhang	665	First-principles study on the optical properties of NaNO ₂ in the ferroelectric and paraelectric phase
Y. Uehara, T. Matsumoto and S. Ushioda	671	Identification of electronic transitions localized at a single oxygen atom adsorbed on $Cu(110)$ - (2×1) surface
S.M. Loureiro, C. Kealhofer, C. Felser and R.J. Cava	675	Structure and superconductivity in LnNi ₂ B ₂ C: comparison of calculation and experiment
S. Agarwal, G.L. Sharma and R. Manchanda	681	Electrical conduction in (Ba, Sr)TiO ₃ thin film MIS capacitor under humid conditions
	I	Volume Index
	XI	Author Index
	XVII	Instructions to Authors
	XIX	Keywords



